

isc Silicon NPN Power Transistor

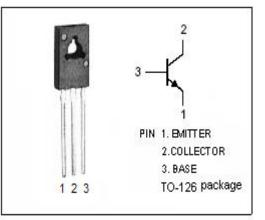
BD723

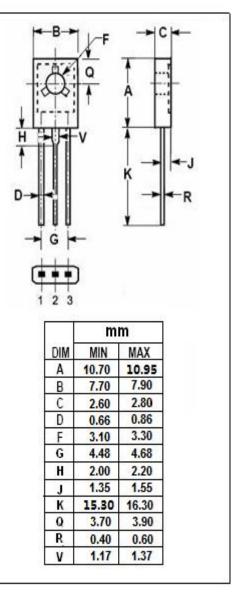
DESCRIPTION

- DC Current Gain-
- : h_{FE}= 40@ I_C= 0.5A
- Collector-Emitter Breakdown Voltage -
- : V_{(BR)CEO}= 100V(Min)
- Complement to type BD724
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

• Designed for use in audio output and general purpose amplifier applications.





ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	YMBOL PARAMETER		UNIT			
V _{CBO}	Collector-Base Voltage	100	V			
V _{CEO}	Collector-Emitter Voltage	100	V			
V_{EBO}	Emitter-Base Voltage	5	V			
Ι _C	Collector Current-Continuous	4	А			
I _{CM}	Collector Current-Peak	7	А			
I _B	Base Current-Continuous	1	А			
Pc	Collector Power Dissipation @ Tc=25°C		W			
TJ	Junction Temperature	150	°C			
T _{stg}	T _{stg} Storage Temperature Range		°C			
Pc TJ	PcCollector Power Dissipation @ $T_c=25^{\circ}C$ T_JJunction Temperature		W °C			

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.5	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	100	°C/W



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ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 30mA ; I _B = 0	100			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 2A; I _B = 0.2A			1.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 2A; V _{CE} = 4V			1.4	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 100V; I _E = 0			50	μ Α
		V _{CB} = 50V; I _E = 0; T _C = 150°C			1	mA
I _{CEO}	Collector Cutoff Current	V _{CE} = 50V; I _B = 0			0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			0.2	mA
h _{FE-1}	DC Current Gain	I _C = 0.5A; V _{CE} = 4V	40			
h _{FE-2}	DC Current Gain	I _C = 2A; V _{CE} = 4V	20			
f⊤	Current-Gain—Bandwidth Product	I _C = 0.5A; V _{CE} = 4V	3			MHz

Switching Times

t _{on}	Turn-On time		0.3	μ s
t _{off}	Turn-Off time	I _C = 1A; I _{B1} = -I _{B2} = 0.1A;V _{CC} = 20V	1.5	μ S

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